

### **Vishay Semiconductors**

TCRT5000L

# Reflective Optical Sensor with Transistor Output

#### Description

The TCRT5000 and TCRT500L are reflective sensors which include an infrared emitter and phototransistor in a leaded package which blocks visible light. The package includes two mounting clips. TCRT5000L is the long lead version.

#### **Features**

Package type: Leaded

Detector type: Phototransistor

Dimensions:

L 10.2 mm x W 5.8 mm x H 7.0 mm

Peak operating distance: 2.5 mm

• Operating range: 0.2 mm to 15 mm

Typical output current under test: I<sub>C</sub> = 1 mA

· Daylight blocking filter

• Emitter wavelength 950 nm

Lead (Pb)-free soldering released

 Lead (Pb)-free component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC





## **Applications**

TCRT5000

Position sensor for shaft encoder

Top view

- Detection of reflective material such as paper, IBM cards, magnetic tapes etc.
- Limit switch for mechanical motions in VCR
- · General purpose wherever the space is limited

#### **Order Instructions**

Part Number	Remarks	Minimum Order Quantity
TCRT5000	3.5 mm lead length	4500 pcs, 50 pcs/tube
TCRT5000L	15 mm lead length	2400 pcs, 48 pcs/tube

#### **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

#### Input (Emitter)

Parameter	Test condition	Symbol	Value	Unit
Reverse voltage		V <sub>R</sub>	5	V
Forward current		I <sub>F</sub>	60	mA
Forward surge current	t <sub>p</sub> ≤ 10 μs	I <sub>FSM</sub>	3	Α
Power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>V</sub>	100	mW
Junction temperature	一方切吗	Tj	100	°C

# **Vishay Semiconductors**



## **Output (Detector)**

Parameter	Test condition	Symbol	Value	Unit
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	5	V
Collector current		I <sub>C</sub>	100	mA
Power dissipation	T <sub>amb</sub> ≤ 55 °C	P <sub>V</sub>	100	mW
Junction temperature		Tj	100	°C

#### Sensor

Parameter	Test condition	Symbol	Value	Unit
Total power dissipation	T <sub>amb</sub> ≤ 25 °C	P <sub>tot</sub>	200	mW
Operation temperature range		T <sub>amb</sub>	- 25 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 25 to + 100	°C
Soldering temperature	2 mm from case, t ≤ 10 s	T <sub>sd</sub>	260	°C

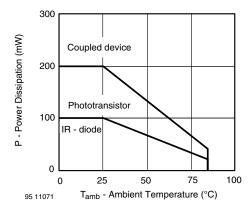


Figure 1. Power Dissipation Limit vs. Ambient Temperature

#### **Electrical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

# Input (Emitter)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I <sub>F</sub> = 60 mA	$V_{F}$		1.25	1.5	V
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz	C <sub>j</sub>		17		pF
Radiant intensity	$I_F = 60 \text{ mA}, t_P = 20 \text{ ms}$	Ι <sub>Ε</sub>			21	mW/sr
Peak wavelength	I <sub>F</sub> = 100 mA	$\lambda_{P}$	940			nm
Virtual source diameter	Method: 63 % encircled energy	Ø		2.1		mm

## **Output (Detector)**

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector emitter voltage	$I_C = 1 \text{ mA}$	$V_{CEO}$	70			V
Emitter collector voltage	I <sub>E</sub> = 100 μA	V <sub>ECO</sub>	7			V
Collector dark current	V <sub>CE</sub> = 20 V, I <sub>F</sub> = 0, E = 0	I <sub>CEO</sub>		10	200	nA

www.vishay.com Rev. 1.6, 04-Sep-06



# **Vishay Semiconductors**

#### **Sensor**

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Collector current	$V_{CE} = 5 \text{ V, } I_{F} = 10 \text{ mA,}$ D = 12 mm	I <sub>C</sub> <sup>1,2)</sup>	0.5	1	2.1	mA
Collector emitter saturation voltage	I <sub>F</sub> = 10 mA, I <sub>C</sub> = 0.1 mA, D = 12 mm	V <sub>CEsat</sub> 1,2)			0.4	V

<sup>1)</sup> See figure 3

 $<sup>^{2)}</sup>$  Test surface: Mirror (Mfr. Spindler a. Hoyer, Part No 340005)

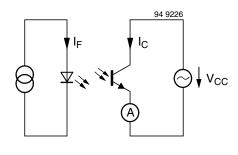


Figure 2. Test Circuit

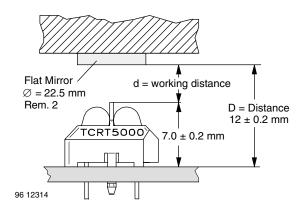


Figure 3. Test Circuit

## **Typical Characteristics**

 $T_{amb}$  = 25 °C, unless otherwise specified

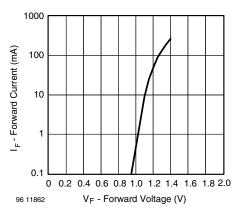


Figure 4. Forward Current vs. Forward Voltage

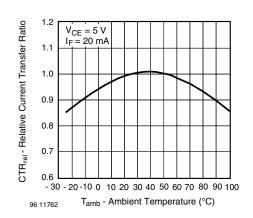


Figure 5. Relative Current Transfer Ratio vs.
Ambient Temperature

# Vishay Semiconductors



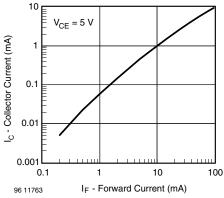


Figure 6. Collector Current vs. Forward Current

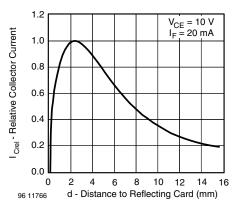


Figure 9. Relative Collector Current vs. Distance

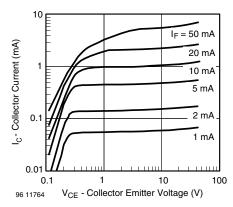


Figure 7. Collector Emitter Saturation Voltage vs. Collector Current

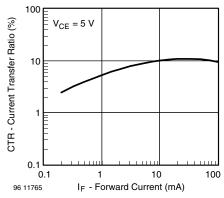


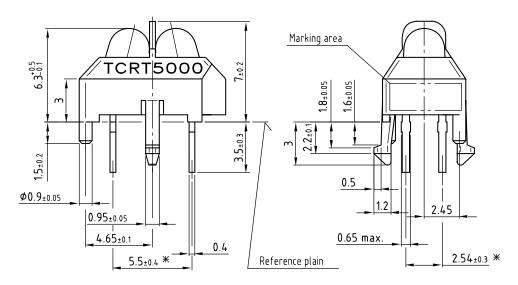
Figure 8. Current Transfer Ratio vs. Forward Current

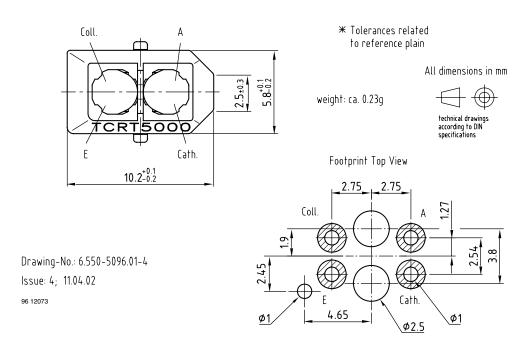




# **Vishay Semiconductors**

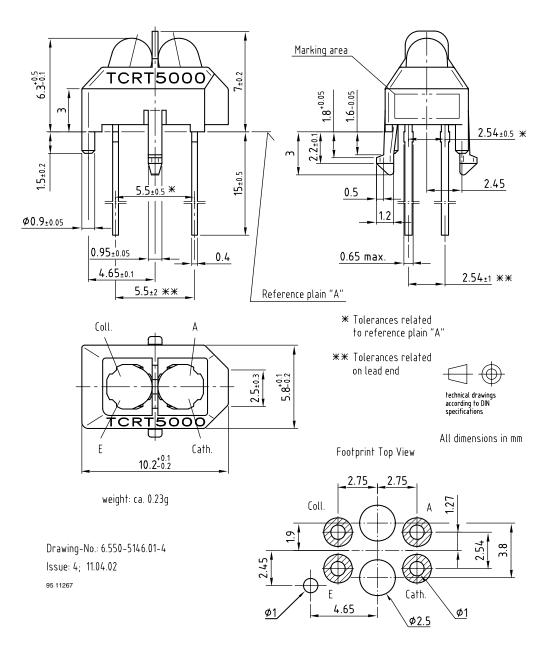
# **Package Dimensions in mm**





# **Vishay Semiconductors**

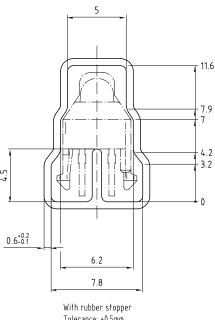






# **Vishay Semiconductors**

# **TCRT5000, Tube Dimensions**

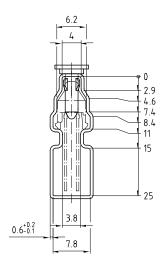


Tolerance: ±0.5mm Length: 575±1mm

All dimensions in mm

Drawing-No.: 9.700-5139.01-4 Issue: 1; 10.05.00

## TCRT5000L, Tube Dimensions



With stopper pins Tolerance: ±0.5mm Length: 575±1mm

All dimensions in mm

Drawing-No.: 9.700-5178.01-4 Issue: 1; 25.02.00 <sup>20299</sup>

#### **Vishay Semiconductors**



#### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

www.vishay.com Document Number 83760 Rev. 1.6, 04-Sep-06





Vishay

#### **Disclaimer**

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.

Document Number: 91000 www.vishay.com